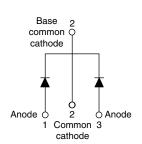


VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

Schottky Rectifier, 2 x 10 A





| PRODUCT SUMMARY | | | | | |
|----------------------------------|----------------|--|--|--|--|
| Package | TO-220AB | | | | |
| I _{F(AV)} | 2 x 10 A | | | | |
| V_R | 150 V | | | | |
| V _F at I _F | 0.66 V | | | | |
| I _{RM} max. | 5 mA at 125 °C | | | | |
| T _J | 175 °C | | | | |
| Diode variation | Common cathode | | | | |
| E _{AS} | 2.45 mJ | | | | |

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-------------------------------------|--|-------------|----|--|--|--|--|
| SYMBOL CHARACTERISTICS VALUES UNITS | | | | | | | |
| I _{F(AV)} | Rectangular waveform | 20 | A | | | | |
| V _{RRM} | | 150 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 1030 | A | | | | |
| V _F | 10 A _{pk} , T _J = 125 °C (per leg) | 0.66 | V | | | | |
| T _J | Range | - 55 to 175 | °C | | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|----------------|----------------|-------|--|--|
| PARAMETER | SYMBOL | VS-20CTQ150PbF | VS-20CTQ150-N3 | UNITS | | |
| Maximum DC reverse voltage | V _R | 150 150 | | V | | |
| Maximum working peak reverse voltage | V _{RWM} | 150 | 130 | V | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|---|--------------------|---|--|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST COND | ITIONS | VALUES | UNITS | | |
| Maximum average per leg | | 50 % duty cycle at T _C = 154 °C, rectangular waveform | | 10 | Α | | |
| See fig. 5 per device | I _{F(AV)} | | | 20 | ^ | | |
| Maximum peak one cycle | | 5 μs sine or 3 μs rect. pulse | Following any rated load | 1030 | А | | |
| non-repetitive surge current per leg See fig. 7 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | condition and with rated V _{RRM} applied | 180 | | | |
| Non-repetitive avalanche energy per leg | E _{AS} | T _J = 25 °C, I _{AS} = 0.7 A, L = 10 mH | | 2.45 | mJ | | |
| Repetitive avalanche current per leg | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 0.7 | А | | |



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Vishay Semiconductors

| ELECTRICAL SPECIFICATIONS | | | | | | | |
|--|--------------------------------|---|-------------------------|------|--------|-------|--|
| PARAMETER | SYMBOL | TEST CO | TEST CONDITIONS | | | UNITS | |
| Maximum forward voltage drop per leg See fig. 1 | | 10 A | T 05 00 | 0.80 | 0.88 | V | |
| | V _{FM} ⁽¹⁾ | 20 A | T _J = 25 °C | 0.90 | 1.0 | | |
| | V _{FM} ('') | 10 A | T 105 °C | 0.63 | 0.66 | | |
| | | 20 A | T _J = 125 °C | 0.73 | 0.77 | | |
| Maximum reverse leakage current per leg | I | T _J = 25 °C | V_{R} = Rated V_{R} | 3.0 | 25 | μΑ | |
| See fig. 2 | I _{RM} | T _J = 125 °C | VR = nateu VR | 2.7 | 5.0 | mA | |
| Typical junction capacitance per leg | C _T | V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C | | - | 280 | pF | |
| Typical series inductance per leg | L _S | Measured lead to lead 5 mm from package body | | - | 8.0 | nH | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | - | 10 000 | V/µs | |

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|---------|-----------------------------------|--|-------------|------------|--|--|
| PARAMETER | | SYMBOL | SYMBOL TEST CONDITIONS | | UNITS | | |
| Maximum junction and storage temperature range | 9 | T _J , T _{Stg} | | - 55 to 175 | °C | | |
| Maximum thermal resistance, junction to case per leg | | В | DC operation | 2.0 | | | |
| Maximum thermal resistance, junction to case per package | | R _{thJC} | DC operation | 1.0 | °C/W | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased (Only for TO-220) | 0.50 | | | |
| Approximate weight | | | | 2 | g | | |
| Approximate weight | | | | 0.07 | OZ. | | |
| Manualina taun | minimum | | | 6 (5) | kgf · cm | | |
| Mounting torque — | maximum | | | 12 (10) | (lbf · in) | | |
| Marking device | | | Case style TO-220AB | 20CTQ150 | | | |



Vishay Semiconductors

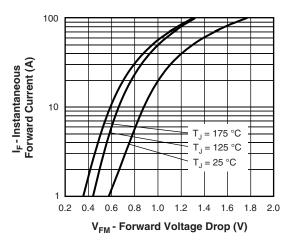


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

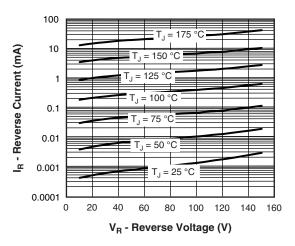


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

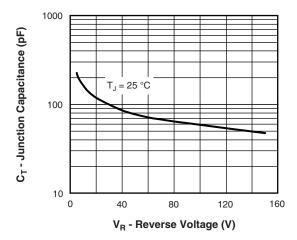


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

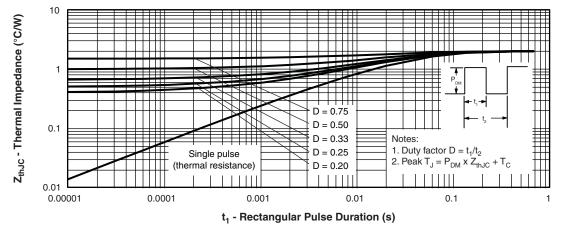


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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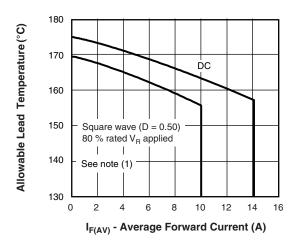


Fig. 5 - Maximum Average Forward Current vs.
Allowable Lead Temperature

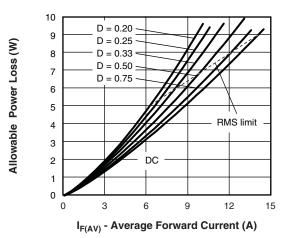


Fig. 6 - Maximum Average Forward Dissipation vs.

Average Forward Current

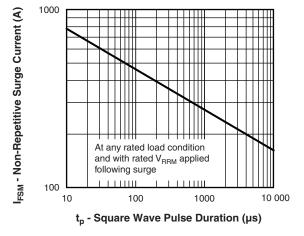


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

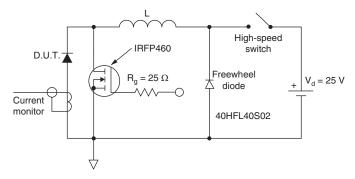


Fig. 8 - Unclamped Inductive Test Circuit

Note

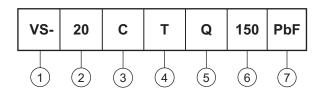
Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (20 = 20 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

Voltage ratings (150 = 150 A)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-20CTQ150PbF | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-20CTQ150-N3 | 50 | 1000 | Antistatic plastic tube | | | | |

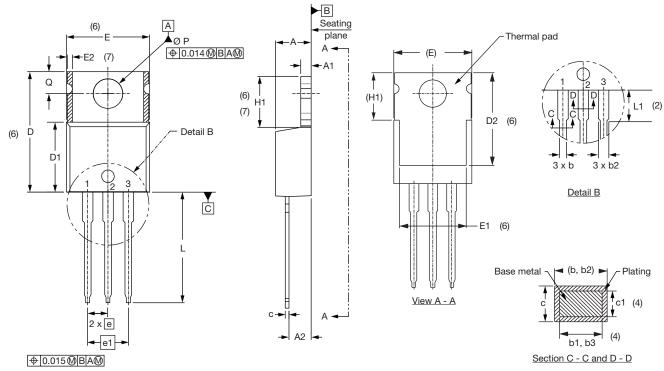
| LINKS TO RELATED DOCUMENTS | | | | | | |
|--|--------------|--------------------------|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?95222</u> | | | | | | |
| Dort marking information | TO-220AB PbF | www.vishay.com/doc?95225 | | | | |
| Part marking information | TO-220AB -N3 | www.vishay.com/doc?95028 | | | | |



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments



- Anode/open
 Cathode
- 3. Anode

Diodes

Conforms to JEDEC outline TO-220AB

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|--------|--------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |

| evi | MBOL | MILLIN | IETERS | INC | HES | NOTES |
|-----|---------|------------|--------|-------|-------|-------|
| 311 | STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| | Е | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| | E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| | E2 | - | 0.76 | - | 0.030 | 7 |
| | е | 2.41 | 2.67 | 0.095 | 0.105 | |
| | e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| | H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6, 7 |
| | L | 13.52 | 14.02 | 0.532 | 0.552 | |
| | L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| (| ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | |
| | Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| | θ | 90° to 93° | | 90° t | o 93° | |
| | | | | | | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



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Vishay

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